High-PSRR, Low-Noise, Low-Dropout, 300mA

CMOS Linear Regulator

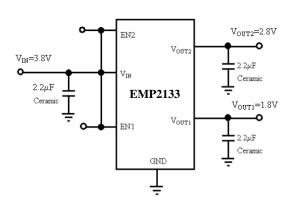
General Description

The EMP2133 series is a family of dual-channel CMOS linear regulators featuring ultra-high power supply rejection ratio (PSRR), low output voltage noise, low dropout voltage, low quiescent current and fast transient response. It guarantees delivery of 300mA output current per regulator, and supports preset output voltages ranging from 1.2V to 3.3V with 0.1V increment (except for 1.85V and 2.85V).

The EMP2133 is well suited for portable battery-powered application which requires high efficiency, low noise and small board space. With 130mV low dropout voltage at 300mA output current, EMP2133 sustains high PSRR at very low input voltage which is common in battery-powered application. The EMP2133 also features $110\mu V_{RMS}$ low output voltage noise without the presence of a noise bypass capacitor, which fits the application where noise and board space are both concerned.

Each regulator in the EMP2133 can be turned off independently, further prolonging the battery life. Internally build-in thermal protection and over-current protection provide additional safety for the end use. The EMP2133 is available in miniature SOT-23-6 and TSOP-6 package.

Typical Application Diagram



Features

- Miniature SOT-23-6 package
- 300mA guaranteed output current
- 70dB typical PSRR at 1kHz (55dB typical at 10KHz)
- 110µV_{RMS} output voltage noise (10Hz to 100kHz)
- 130mV typical dropout at 300mA
- 150µA typical quiescent current
- Less than 1µA typical shutdown mode
- Auto-discharge during chip disable
- Fast line and load transient response
- 35µs typical turn-on time
- 2.5V to 5.5V input range
- Stable with small ceramic output capacitors
- Over temperature and over current protection
- ±2% output voltage tolerance

Applications

- Wireless handsets
- PCMCIA cards
- DSP core power
- Hand-held instruments
- Battery-powered systems
- Portable information appliances

Typical Performance Characteristics

-10 VIN=3.8V, Iout1=Iout2=30mA -20 -25 -30 35 -40 -45 SRR (dB) -60 -55 -60 -65 .70 V_{OUT1}=1.8V V_{OUT2}=2.8V Frequency (Hz)

PSRR vs. Frequency

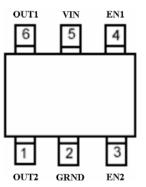
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Publication Date : Jun. 2009Revision : 3.01/13



Pin Configuration

SOT-23-6



Order information

EMP21	EMP2133-XXVC06GRR/NRR					
XX	Voltage Code					
VC06	SOT-23-6 Package					
GRR	RoHS (Pb Free)					
	Rating: -40 to 85°C					
	Package in Tape & Reel					
NRR	RoHS & Halogen free (By Request)					
	Rating: -40 to 85°C					
	Package in Tape & Reel					

Pin Functions

Name	SOT-23-6	Function	
	TSOP-6	Function	
OUT2	1	Output Voltage Feedback of Regulator 2	
GRND	2	Ground Pin.	
		Enable Input of Regulator 2. Set regulator 2 into the disable mode by pulling the EN2 pin	
EN2		low. To keep regulator 2 on during normal operation, connect the EN2 pin to VIN. The	
		EN2 pin must not exceed VIN under all operating conditions.	
		Enable Input of Regulator 1. Set regulator 1 into the disable mode by pulling the EN1 pin	
EN1	4	low. To keep regulator 1 on during normal operation, connect the EN1 pin to VIN. The	
		EN1 pin must not exceed VIN under all operating conditions.	
VIN	5	Supply Voltage Input. Require a minimum input capacitor of close to $1\mu F$ to ensure	
	5	stability and sufficient decoupling from the ground pin.	
OUT1	6	Output Voltage Feedback of Regulator 1	



Order, Mark & Packing Information

No. of PIN	EN1	EN2	Vout1	Vout2	Marking	Product ID	Package	
			3.0	3.0	E		EMP2133-00VC06GRR	3K units Tape & Reel
			1.8	3.0		EMP2133-01VC06GRR	3K units Tape & Reel	
			1.8	2.8			EMP2133-02VC06GRR	3K units Tape & Reel
			2.5	3.3	6 5 4	EMP2133-03VC06GRR	3K units Tape & Reel	
			2.8	3.3	2133 Tracking Code	EMP2133-04VC06GRR	3K units Tape & Reel	
6	Y	Y	1.8	3.3		Tracking Code	EMP2133-05VC06GRR	3K units Tape & Reel
		2.85 2.8	2.85	2.85			EMP2133-06VC06GRR	3K units Tape & Reel
						2.8	1.8	1 2 3 OUT2 GRND EN2
			3.3	3 2.8		EMP2133-08VC06GRR	3K units Tape & Reel	
			2.5	1.8		EMP2133-10VC06GRR	3K units Tape & Reel	
			1.2	2.8		EMP2133-11VC06GRR	3K units Tape & Reel	

Absolute Maximum Ratings (Notes 1, 2)

$VIN, V_{OUT1}, V_{OUT2}, V_{EN1}, V_{EN2}$	-0.3V to 6.5V		
Power Dissipation	(Note 3)	Thermal Resistance (θ_{JA})	
Storage Temperature Range	-65°C to160°C	SOT-23-6	250°C/W
Junction Temperature (TJ)	150°C		
Lead Temperature (10 sec.)	260°C	Operating Ratings (Note 1, 2)	
ESD Rating		Temperature Range	-40°C to 85°C
HBM (Note 5)	2kV	Supply Voltage	2.5V to 5.5V
мм	200V		

Electrical Characteristics

Unless otherwise specified, all limits guaranteed for $V_{IN} = V_{OUT} + 1V$ (Note 6), $V_{EN1} = V_{EN2} = VIN$, $C_{IN} = C_{OUT} = 2.2\mu$ F, $T_J = 25^{\circ}$ C. Boldface limits apply for the operating temperature extremes: -40°C and 85°C.

Symbol	Parameter	Conditions	Min	Typ (Note 7)	Max	Units	
VIN	Input Voltage		2.5		5.5	V	
		I _{OUT} = 30mA	-2		+2	% of	
ΔV_{OTL}	Output Voltage Tolerance	$V_{IN} = V_{OUT (NOM)} + 1V$, (Note 6)	-3		+3	Vout (NOM)	
I _{OUT}	Maximum Output Current	Average DC Current Rating	300			mA	
ILIMIT	Output Current Limit			600		mA	
	Surger Current	I _{OUT1} = I _{OUT2} = 0mA		150			
lq	Supply Current	I _{OUT1} = I _{OUT2} = 300mA		250		μA	
	Shutdown Supply Current	EN1 = EN2 = GND		0.001			
N/	Dropout Voltage	I _{OUT} = 30mA		13			
V_{DO}	(Note 4), (Note 6)	I _{OUT} = 300mA		130		mV	
Power-supply rejection rati		f = 100Hz		75			
	VIN=3.8V, V _{OUT} =2.8V	f = 1kHz		70		dB	
PSRR	I _{OUT} =10mA	f = 10kHz		55			
POKK	Power-supply rejection ratio	f = 100Hz		68			
	VIN=3.8V, V _{OUT} =2.8V	f = 1kHz		68			
	I _{OUT} =150mA	f = 10kHz		55			
ΔV_{OUT}	Line Regulation	$I_{OUT} = 30 \text{mA}$, $(V_{OUT} + 1 \text{V}) \le V_{IN} \le$ 5.5V, (Note 6)	-0.1	0.01	0.1	%/V	
	Load Regulation	1mA ≤ I _{OUT} ≤ 300mA		0.0003		%/mA	
en	Output Voltage Noise	V _{OUT} =2.8V, I _{OUT} = 30mA, 10Hz ≤ f ≤ 100kHz (Note 8)		110		μV _{RMS}	
V	Engble Innut Threshold	V_{IH} , $(V_{OUT} + 0.5V) \le V_{IN} \le 5.5V$ (Note 6)	1.2				
V_{EN}	Enable Input Threshold	V_{IL} , $(V_{OUT} + 0.5V) \le V_{IN} \le 5.5V$ (Note 6)			0.4	- V	
	Thermal Shutdown			170			
T _{SD}	Temperature			170		°C	
	Thermal Shutdown Hysteresis			30			

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T _{ON}	Turn-On Time	V _{out} at 95% of Final Value	35	μs
TOFF	Turn-Off Time	Iout=0mA (Note 9)	2.4	ms

Note 1: Absolute Maximum ratings indicate limits beyond which damage may occur. Electrical specifications are not applicable when the device is operated outside of its rated operating conditions.

Note 2: All voltages are defined and measured with respect to the potential at the ground pin.

Note 3: Maximum Power dissipation for the device is calculated using the following equations:

$$P_{D} = \frac{T_{J(MAX)} - T_{A}}{\theta_{JA}}$$

where $T_{J(MAX)}$ is the maximum junction temperature, T_A is the ambient temperature, and θ_{JA} is the junction-to-ambient thermal resistance. E.g. for the SOT-23-6 package $\theta_{JA} = 250^{\circ}$ C/W, $T_{J(MAX)} = 150^{\circ}$ C and using $T_A = 25^{\circ}$ C, the maximum power dissipation is found to be 500mW. The derating factor (-1/ θ_{JA}) = -4mW/°C, thus below 25°C the power dissipation figure can be increased by 4mW per degree, and similarity decreased by this factor for temperatures above 25°C.

Note 4: Dropout voltage is measured by reducing V_{IN} until V_{OUT} drops 100mV from its nominal value at V_{IN} -V_{OUT} =1V. Dropout voltage does not apply to the regulator versions with V_{OUT} less than 2.5V.

Note 5: Human body model: $1.5k\Omega$ in series with 100pF.

Note 6: Condition does not apply to input voltages below 2.5V since this is the minimum input operating voltage.

Note 7: Typical Values represent the most likely parametric norm.

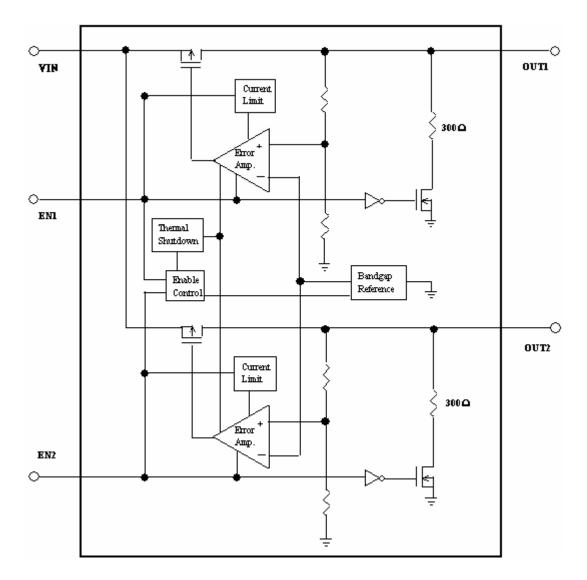
Note 8: For different output voltage, the noise can be approximately calculated using the following formula:

Noise =
$$V_{OUT} \times 38 (\mu V_{RMS})$$

Note 9: Turn-off time is time measured between the enable input just decreasing below V_{IL} and the output voltage just decreasing to 10% of its nominal value.

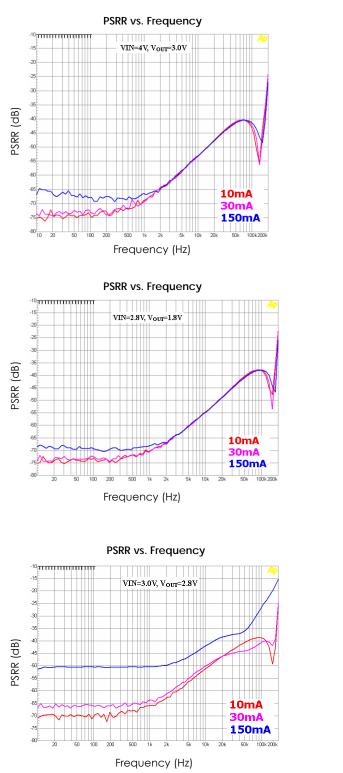


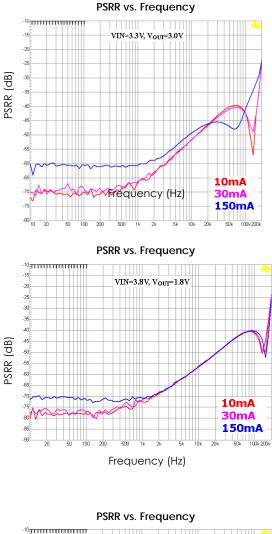
Functional Block Diagram

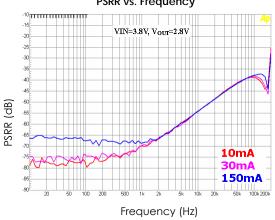


Typical Performance Characteristics

Unless otherwise specified, VIN = $V_{OUT (NOM)}$ + 1V, C_{IN} = C_{OUT} = 2.2µF, T_A = 25°C, V_{EN1} = V_{EN2} = VIN.

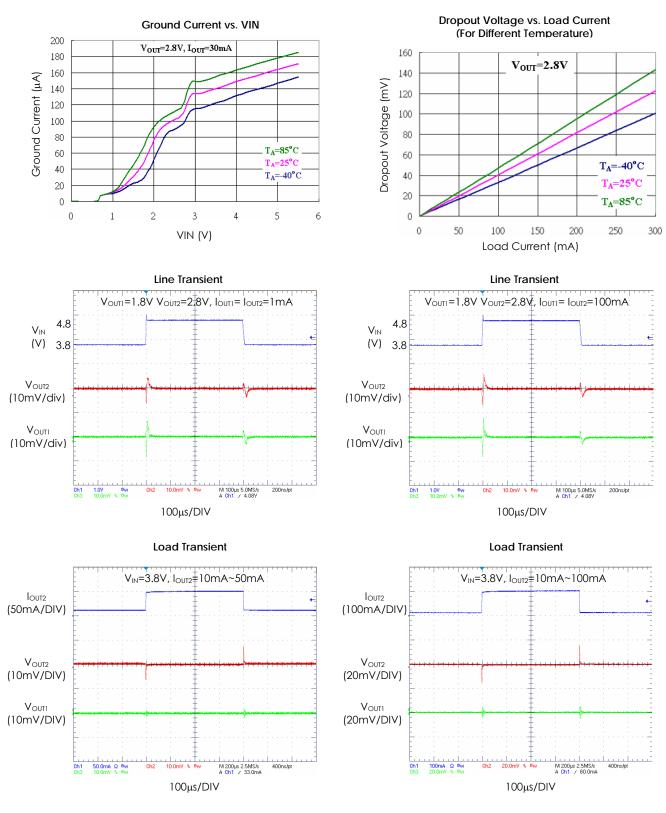






Typical Performance Characteristics

Unless otherwise specified, VIN = Vout (NOM) + 1V, CIN = COUT = 2.2µF, TA = 25°C, VEN1 = VEN2 = VIN. (Continued)

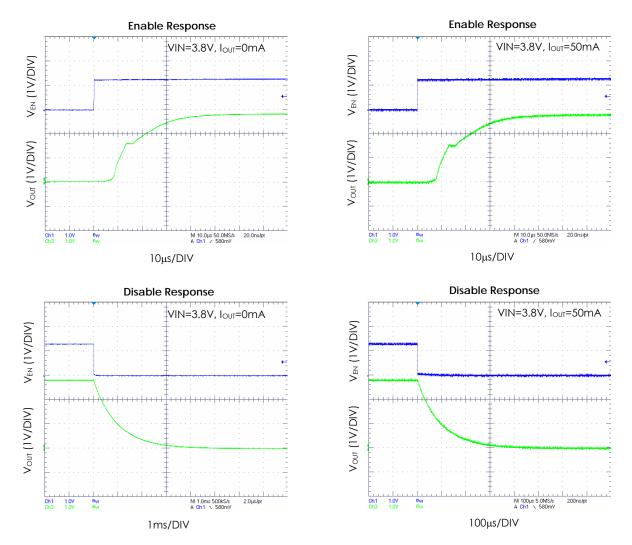


Typical Performance Characteristics

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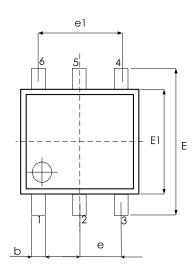
Unless otherwise specified, VIN = V_{OUT (NOM)} + 1V, C_{IN} = C_{OUT} = 2.2µF, T_A = 25°C, V_{EN1} = V_{EN2} = VIN. (Continued)

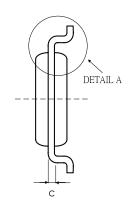


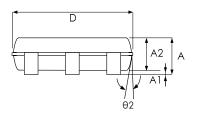


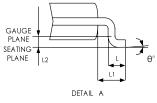
Physical Dimensions

SOT-23-6









_			
	—	1.45	
_	_	0.15	
0.9	1.15	1.3	
0.3	_	0.5	
0.08	_	0.22	
2.90 BSC.			
2.80 BSC.			
1.60 BSC.			
0.95 BSC			
1.90 BSC			
0.3	0.45	0.6	
0.60 REF			
0.25 REF			
0	4	8	
5	10	15	
	0.3 0.08 0.3 0.3 0.3	0.3 − 0.08 − 2.90 BSC. 2.80 BSC. 1.60 BSC. 0.95 BSC 1.90 BSC 0.3 0.45 0.60 REF 0.25 REF 0 4	

UNIT: MM



Old Order, Mark & Packing Information

No. of PIN	EN1	EN2	Vout1	Vout2	Option	Old Marking	Package																		
	Y Y		3.0	3.0	00	1300 Date code	3K units Tape & Reel																		
						Ý	Y	Y	Y Y												1.8	3.0	01	1301 Date code	3K units Tape & Reel
		Y Y	Y	Y	Y																				
6										2.5	3.3	03	1303 Date code	3K units Tape & Reel											
										2.8	3.3	04	1304 Date code	3K units Tape & Reel											
						1.	1.8	3.3	05	1305 Date code	3K units Tape & Reel														
				2.85	2.85	06	1306 Date code	3K units Tape & Reel																	



Revision History

Revision	Date	Description
3.0	2009.06.08	EMP transferred from version 2.3



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